

## Product Summary

<b>BV<sub>DSS</sub></b>	<b>R<sub>DS(ON)</sub> Max</b>	<b>I<sub>D</sub> T<sub>C</sub> = +25°C</b>
60V	7.2mΩ @ V <sub>GS</sub> = 10V	98A

## Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

## Applications

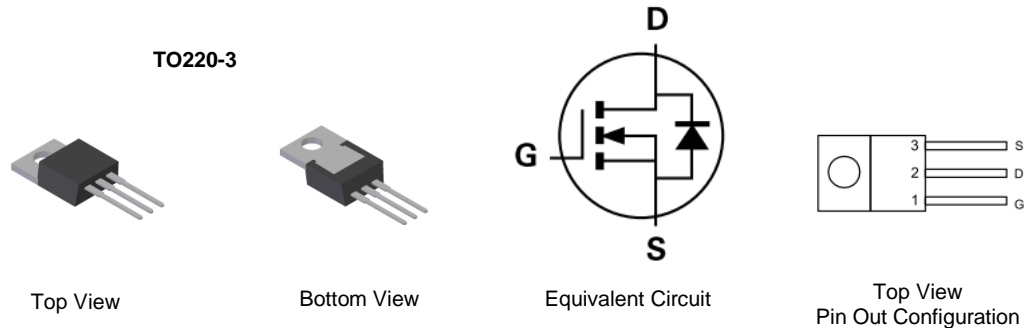
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

## Features

- 100% Unclamped Inductive Switching – Ensures More Reliable and Robust End Application
- Low Input Capacitance
- Low Input/Output Leakage
- **Lead-Free Finish; RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

## Mechanical Data

- Case: TO220-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (B)
- Weight: 1.85 grams (Approximate)

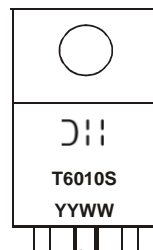


## Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6010SCT	TO220-3	50 Pieces/Tube

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



Ⓜ = Manufacturer's Marking  
 T6010S = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY or YY = Last Digit of Year (ex: 16 = 2016)  
 WW or WW = Week Code (01 to 53)

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	60	V
Gate-Source Voltage	$V_{GSS}$	$\pm 20$	V
Continuous Drain Current (Note 6)	$I_D$	$T_C = +25^\circ\text{C}$	98
		$T_C = +70^\circ\text{C}$	78
Maximum Continuous Body Diode Forward Current (Note 6)	$I_S$	100	A
Pulsed Drain Current (10 $\mu\text{s}$ Pulse, Duty Cycle = 1%)	$I_{DM}$	160	A
Avalanche Current, $L=0.1\text{mH}$	$I_{AS}$	20	A
Avalanche Energy, $L=0.1\text{mH}$	$E_{AS}$	20	mJ

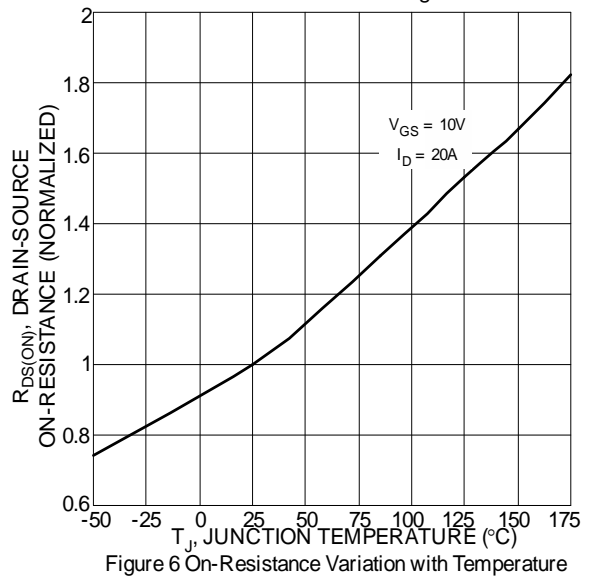
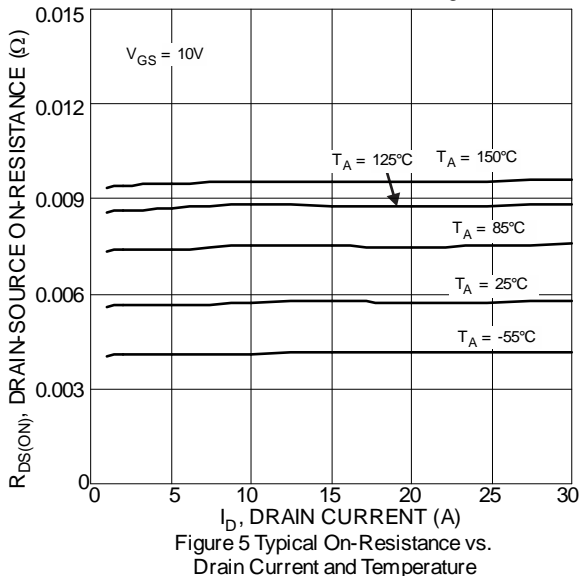
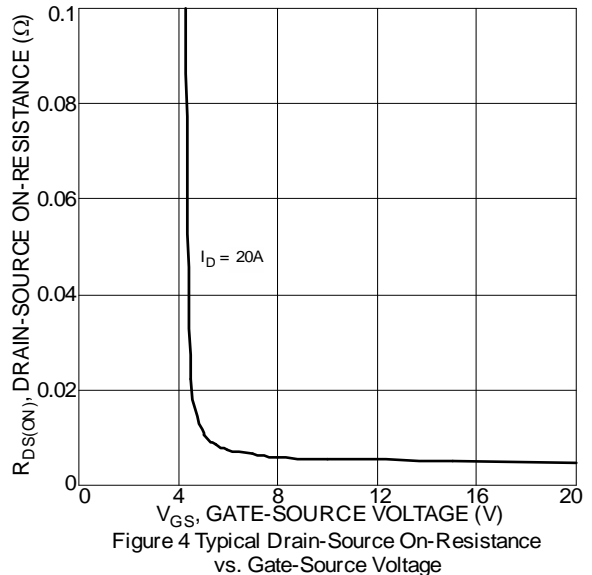
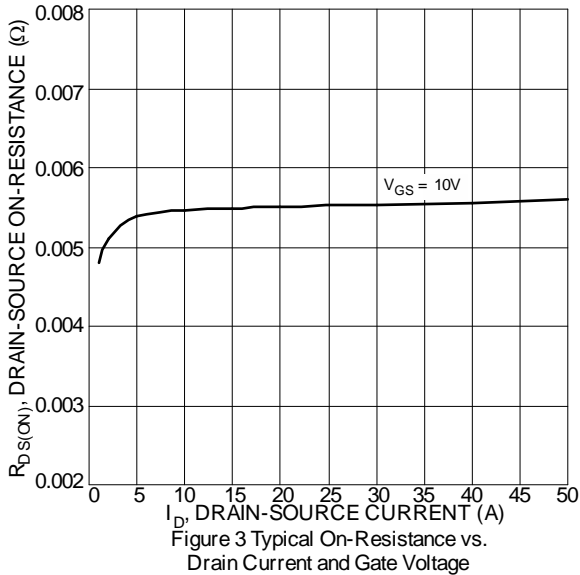
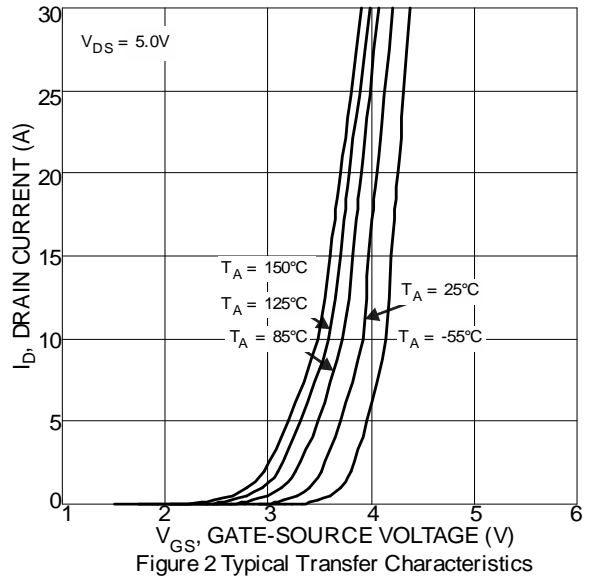
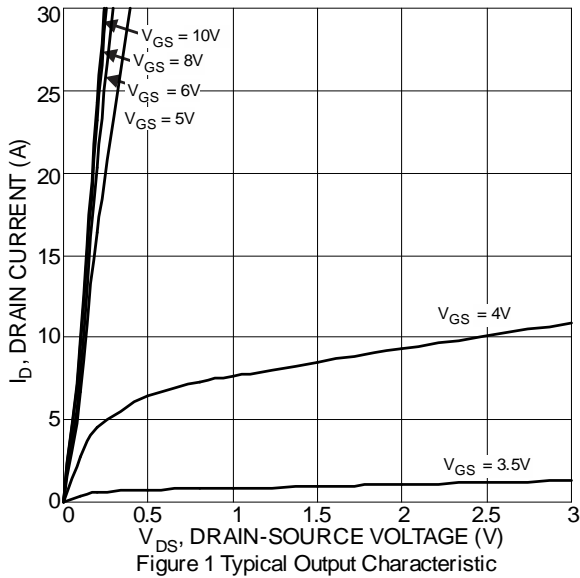
**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	$P_D$	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	52.8	$^\circ\text{C/W}$
Total Power Dissipation (Note 6)	$P_D$	104	W
Thermal Resistance, Junction to Case (Note 6)	$R_{\theta JC}$	1.2	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b> (Note 7)						
Drain-Source Breakdown Voltage	$BV_{DSS}$	60	—	—	V	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$
Zero Gate Voltage Drain Current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 48\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS</b> (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	2	—	4	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	5.5	7.2	m $\Omega$	$V_{GS} = 10\text{V}, I_D = 20\text{A}$
Diode Forward Voltage	$V_{SD}$	—	—	1.3	V	$V_{GS} = 0\text{V}, I_S = 20\text{A}$
<b>DYNAMIC CHARACTERISTICS</b> (Note 8)						
Input Capacitance	$C_{ISS}$	—	1,940	—	pF	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
Output Capacitance	$C_{OSS}$	—	759	—		
Reverse Transfer Capacitance	$C_{RSS}$	—	85.2	—		
Gate Resistance	$R_G$	—	0.55	—	$\Omega$	$V_{DS} = 0\text{V}, V_{GS} = 0\text{V}, f = 1\text{MHz}$
Total Gate Charge	$Q_G$	—	36.3	—	nC	$V_{DS} = 30\text{V}, I_D = 20\text{A}, V_{GS} = 10\text{V}$
Gate-Source Charge	$Q_{GS}$	—	7.5	—		
Gate-Drain Charge	$Q_{GD}$	—	10.5	—		
Turn-On Delay Time	$t_{D(ON)}$	—	5.7	—	ns	$V_{DD} = 30\text{V}, V_{GS} = 10\text{V}, I_D = 20\text{A}, R_G = 3\Omega$
Turn-On Rise Time	$t_R$	—	10.4	—		
Turn-Off Delay Time	$t_{D(OFF)}$	—	16.3	—		
Turn-Off Fall Time	$t_F$	—	11.2	—		
Reverse Recovery Time	$t_{RR}$	—	35.6	—	ns	$I_F = 20\text{A}, di/dt = 100\text{A}/\mu\text{s}$
Reverse Recovery Charge	$Q_{RR}$	—	37.9	—	nC	

- Notes:
5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
  6. Device mounted on infinite heat sink.
  7. Short duration pulse test used to minimize self-heating effect.
  8. Guaranteed by design. Not subject to product testing.



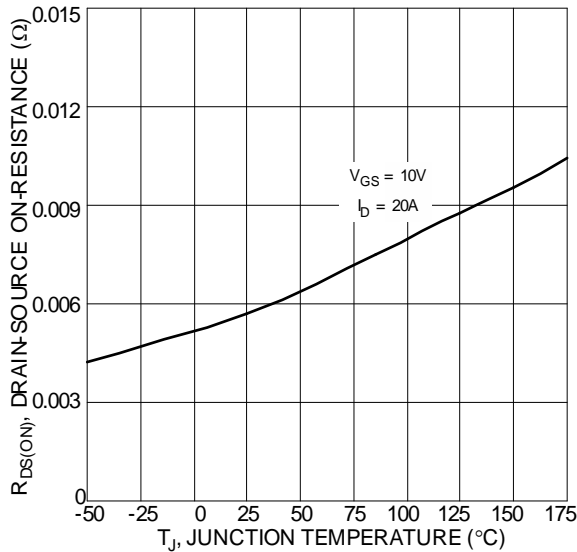


Figure 7 On-Resistance Variation with Temperature

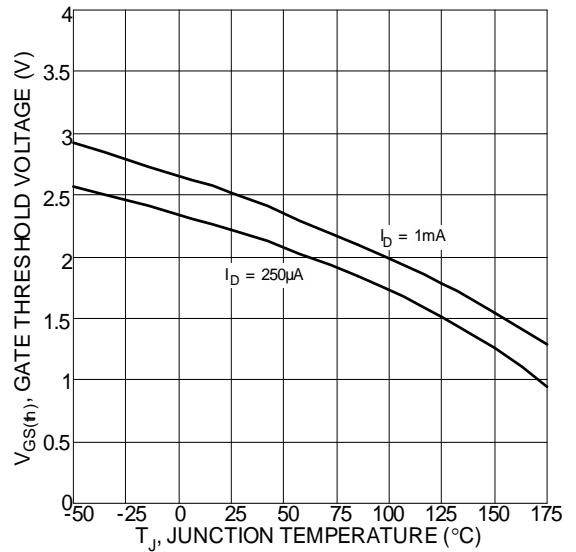


Figure 8 Gate Threshold Variation vs. Ambient Temperature

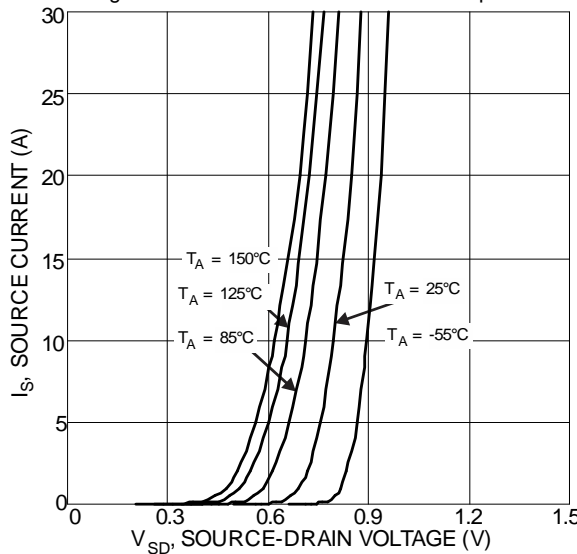


Figure 9 Diode Forward Voltage vs. Current

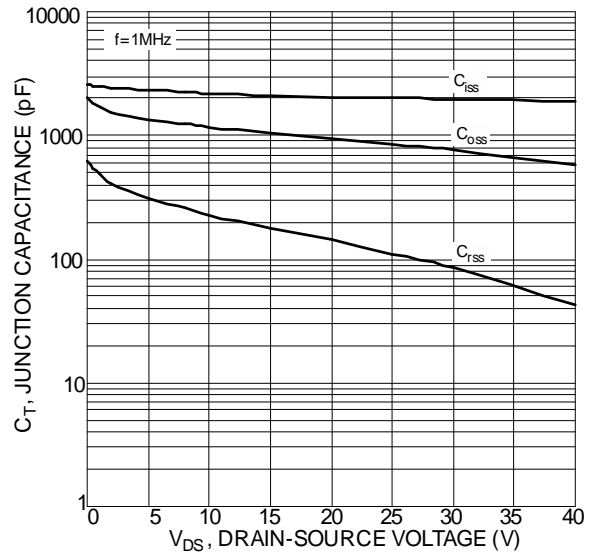


Figure 10 Typical Junction Capacitance

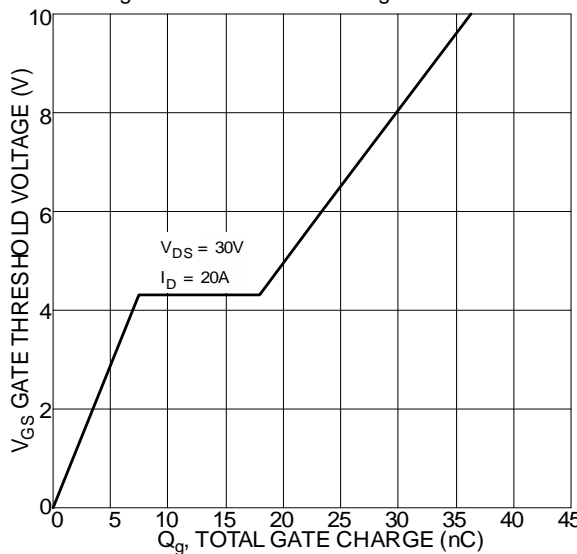


Figure 11 Gate Charge

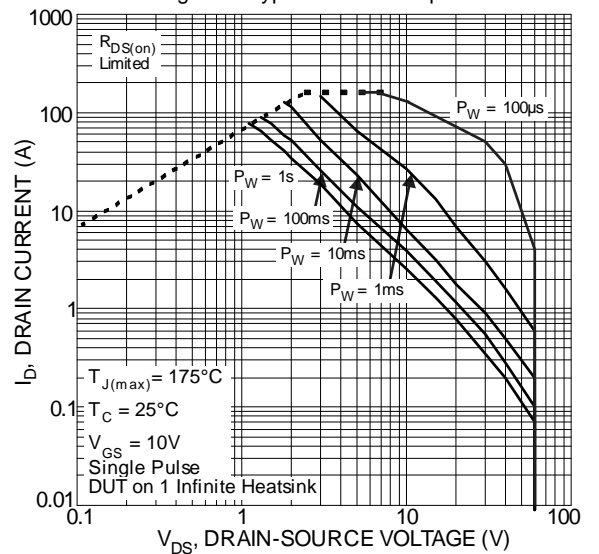
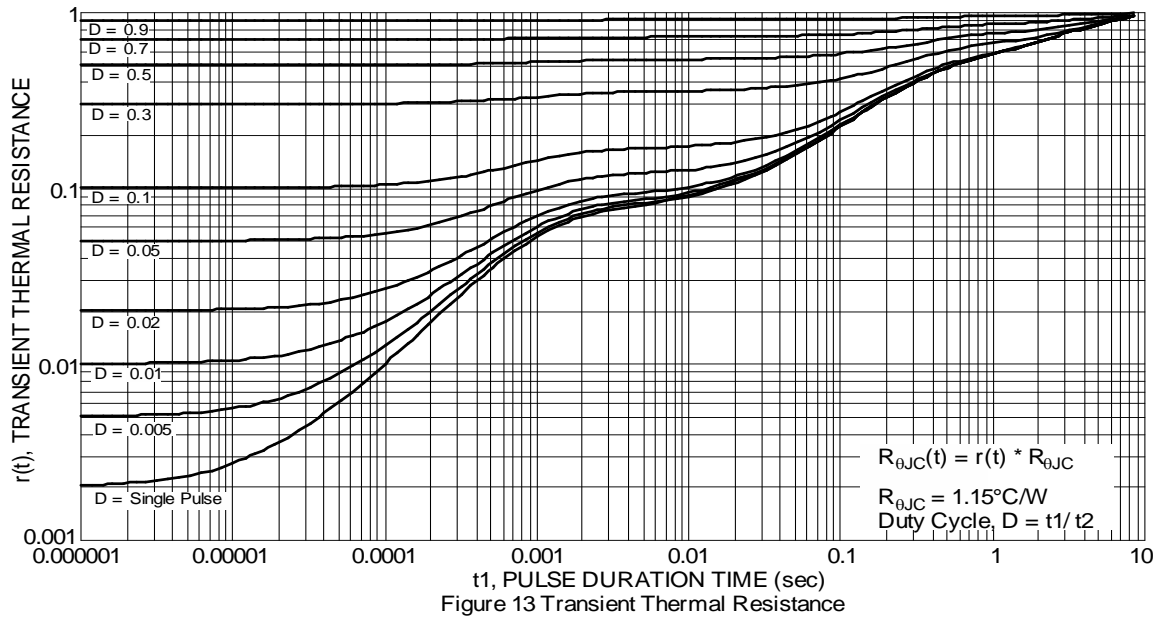


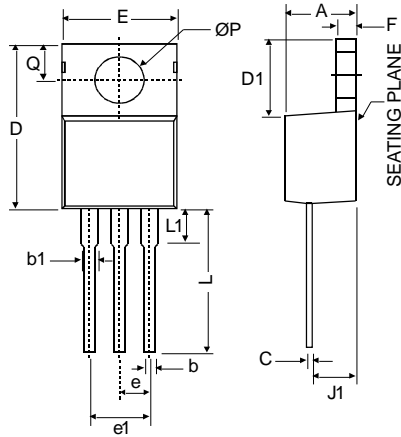
Figure 12 SOA, Safe Operation Area



## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO220-3



TO220-3		
Dim	Min	Max
A	3.55	4.85
b	0.51	1.14
b1	1.14	1.78
C	0.31	1.14
D	14.20	16.50
D1	5.84	6.86
E	9.70	10.70
e	2.79	2.99
e1	4.83	5.33
F	0.51	1.40
J1	2.03	2.92
L	12.72	14.72
L1	3.66	6.35
P	3.53	4.09
Q	2.54	3.43
<b>All Dimensions in mm</b>		

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